Controlled Correlation and Squeezing in Pr³⁺: Y₂SiO₅ to Yield Correlated Light Beams

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We report the generation of twin beams by the parametric amplification four-wave mixing process and triplet beams by the parametric amplification six-wave mixing (PA SWM) process associated with the multiorder fluorescence signals in a Pr³⁺: Y₂SiO₅ crystal. The intensity noise correlation and intensitydifference squeezing result from the nonlinear gain, which can be well controlled by the polarized dressing effect. The correlation value at the resonant position increases due to the double dressing effect; however, such correlation decreases if the triple dressing effect works. Specifically, correlation and squeezing between Stokes and anti-Stokes signals can be also switched by the relative nonlinear phase shift. The generated triplet beams from the PA SWM process have potential applications in three-mode all-optical information processing that can be used in on-chip photonic devices.

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I. INTRODUCTION

As a further step towards integrated quantum photonic devices, it is necessary to miniaturize external light sources to improve their performance, such as their portability, stability, and multifunctionality. To achieve such light sources, methods that are based on traditional nonlinear optical crystals, especially domain-engineered quadratic nonlinear photonic crystals [1,2], were developed. Recently, a certain valuable extension of the path-entangled states to high-dimensional entanglement from a domaincascaded lithium niobate crystal was reported [3]. On the other hand, rare-earth-doped crystals such as Pr^{3+} : Y₂SiO₅ exhibit unique features in comparison to nonlinear crystals. In these kinds of doped crystals, the "atomlike" properties of the dopant can be kept, in which the atomic coherence can be induced easily when interacting with multiple laser beams. As for the atomic coherence effects in solid-state materials, recent research includes electromagnetically induced transparency [4,5], light velocity reduction and coherent storage [6-8], optical quantum computing [9,10], all-optical routing based on optical storage [11], and enhanced four-wave mixing (FWM) based on atomic coherence [12], to name a few. It is worth mentioning that following the latest developments in intensity squeezed light with FWM in an atomic vapor, one can use the multiwave mixing processes in such rare-earth-doped crystals to generate entangled lights.

In this paper, we report the generation of correlated light beams from a parametric amplification four-wave-mixing (PA FWM) process and a PA six-wave-mixing (PA SWM) process in a Pr^{3+} : Y₂SiO₅ crystal. Two nonlinear cascade optical processes are controlled by adjustable dressing fields, and the results show that the degrees of the threemode correlation and squeezing are induced by the dressed nonlinear gain. The correlation and squeezing can be controlled by the relative nonlinear phase shift caused by the dressing fields. On the other hand, the correlation and squeezing of PA FWM can be switched to anticorrelation and antisqueezing. Such controllable properties have potential applications in all-optical communication and optical information processing on photonic chips.

II. THEORETICAL MODEL

The sample is a 0.05% rare-earth Pr^{3+} -doped Y_2SiO_5 $(Pr^{3+}: Y_2SiO_5)$ crystal, in which the triplet-energy-level ${}^{3}H_{4}$ and singlet-energy-level ${}^{1}D_{2}$ are selected to couple with each other. It is easy to identify the energy levels by investigating the optical spectrum of Pr^{3+} . The degeneracy of the Pr³⁺ energy levels is prohibited due to the crystal field of Y₂SiO₅; the ${}^{3}H_{4}$ and ${}^{1}D_{2}$ states are split into nine and five Stark components, respectively. The five relevant energy levels are δ_0 ($|0\rangle$ and $|1\rangle$), γ_0 ($|2\rangle$), δ_1 ($|3\rangle$), γ^*_0 ($|4\rangle$) in a five-level atomic system as shown in Fig. 1(a). The nature linewidths are about 2 kHz (site I) and 1 kHz (site II) [13]. The input laser beams are along the [010] axis of the

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FIG. 1. Experimental setup. (a) *N*-type four-level atomlike system in Pr^{3+} : Y₂SiO₅. The width of ground state $|0\rangle$ represents the broadened degenerate states. (b) Experimental setup scheme. Flu, fluorescence; D, photomultiplier tube; L, lens. E_2 and E_3 counterpropagate with E_1 .

 Y_2SiO_5 crystal, where the [010] axis is perpendicular to the optical axis. A strong pump beam E_1 (frequency ω_1 , wave vector \mathbf{k}_1 , Rabi frequency G_1 , wavelength 605.97 nm, coupling transition $|0\rangle \leftrightarrow |2\rangle$ with detuning $\Delta_i =$ $\omega_{mn} - \omega_i$, $|1\rangle \leftrightarrow |2\rangle \Delta'_1 = \omega_{21} - \omega_1$, where ω_{mn} denotes the corresponding atomic transition frequency, and ω_i is the laser frequency), E_2 (ω_2 , \mathbf{k}_2, G_2 , 609.27 nm, $|3\rangle \leftrightarrow |2\rangle$, Δ_2), and E_3 (ω_3 , k_3 , G_3 , 607.96 nm, $|0\rangle \leftrightarrow |4\rangle$, Δ_3 , $|1\rangle \leftrightarrow |4\rangle, \Delta'_3$). The Pr³⁺ impurity ions occupy two nonequivalent cation sites (i.e., sites I and II) in the Y₂SiO₅ crystal. The energy levels for site I are labeled by a greek letter without an asterisk, while for site II by an asterisk, as shown in Fig. 1(a). Actually, with the induced dipole-dipole interaction considered, the coupling between the Pr³⁺ ions localized at different cation vacancies in the Y_2SiO_5 crystal can occur [14], so one can treat the two ions (at different sites) as a hetero-nuclear-like molecule. Therefore, one can establish an N-type four-level diagram $(|3\rangle \leftrightarrow |2\rangle \leftrightarrow |1\rangle \leftrightarrow |4\rangle$ or $|3\rangle \leftrightarrow |2\rangle \leftrightarrow |0\rangle \leftrightarrow |4\rangle$), which is composed of one Λ -type $(|3\rangle \leftrightarrow |2\rangle \leftrightarrow |0\rangle$ or $|3\rangle \leftrightarrow |2\rangle \leftrightarrow |1\rangle$) subsystem and one V-type ($|2\rangle \leftrightarrow$ $|0\rangle \leftrightarrow |4\rangle$ or $|2\rangle \leftrightarrow |1\rangle \leftrightarrow |4\rangle$) subsystem. A two-photon coupling process can be implemented by the transition $|2\rangle \leftrightarrow |1\rangle \leftrightarrow |4\rangle.$

In the following theoretical section, we first introduce the nonlinear gain and then interpret that the intensity of such nonlinear gain can be controlled by the dressing effect. Based on the above, we investigate the intensity noise correlation and intensity-difference squeezing in the dressing PA FWM.

A. Spontaneously parametric FWM

The SP FWM process involves a coupled Stokes channel and an anti-Stokes channel and produces twin photons. One can express such SP FWM process with the Hamiltonian [15]

$$H = \frac{\kappa}{v} (\hat{a}^+ \hat{b}^+ + \hat{a} \, \hat{b}), \tag{1}$$

where $\hat{a}^+(\hat{a})$ is the creation (-annihilation) operator that acts on the electromagnetic excitation of the E_S channel, whereas $\hat{b}^+(\hat{b})$ acts on the E_{AS} channel. v is the group velocity of light in the nonlinear medium, and $\kappa_{S,AS} =$ $|-i\varpi_{S,AS}\chi^{(3)}E_1^2/2|$ is the pumping parameter of the SP FWM, which depends on the nonlinearity $\chi^{(3)}$ and the pump-field amplitude. $\rho_{11}^{(0)} \xrightarrow{\omega_1} \rho_{21}^{(1)} \xrightarrow{\omega_{AS}} \rho_{01}^{(2)} \xrightarrow{\omega_1} \rho_{21(S)}^{(3)}$ and $\rho_{00}^{(0)} \xrightarrow{\omega_1} \rho_{21(S)}^{(0)}$ $\rho_{20}^{(1)} \xrightarrow{\omega_S} \rho_{10}^{(2)} \xrightarrow{\omega_1} \rho_{20(AS)}^{(3)}$ are the central frequencies of the generated Stokes and anti-Stokes signals. Different from the case occurring in nonlinear crystals, $\chi^{(3)}$ is a function of the density-matrix elements. A SP FWM process occurs in the paraxial direction due to the so-called self-diffraction phase-matching FWM process generated in a "double- Λ -type" subsystem $[|0\rangle \leftrightarrow |1\rangle \leftrightarrow |2\rangle$ between two vertical dashed lines in Fig. 1(a)]. The strong pumping field E_1 together with the generated Stokes (E_s) and anti-Stokes (E_{AS}) fields satisfy the phase-matching conditions $\mathbf{k}_{S} =$ $2\mathbf{k}_1 - \mathbf{k}_{AS}$ and $\mathbf{k}_{AS} = 2\mathbf{k}_1 - \mathbf{k}_S$. Laser beams E_2 and E_3 (counterpropagating with E_1) can cause resonant absorption and are used only to dress such SP FWM. Thus, only dressed SP FWM can be detected, and the generated fields can be described by the perturbation chains [16,17] $\rho_{11}^{(0)\,\omega_1} \rightarrow \rho_{21}^{(1)\,\omega_{\rm AS}} \rho_{01}^{(2)\,\omega_1} \rightarrow \rho_{21(S)}^{(3)} \ (E_S) \text{ and } \rho_{00}^{(0)\,\omega_1} \rightarrow \rho_{20}^{(1)\,\omega_S} \rho_{10}^{(2)\,\omega_1} \rightarrow \rho_{20(\rm AS)}^{(3)}$ (E_{AS}) . Therefore, one gets [18]

$$\rho_{21(S)}^{(3)} = -iG_{\rm AS}^* G_1^2 / (d_{21}d_{01}d_{21}'), \qquad (2)$$

$$\rho_{20(\text{AS})}^{(3)} = -iG_S^* G_1^2 / (d_{20}d_{10}d_{20}'), \qquad (3)$$

where $G_i = \mu_{ij}E_i/\hbar$ is the Rabi frequency of field E_i with the electric dipole matrix elements μ_{ij} , $d_{20} = \Gamma_{20} + i\Delta_1$, $d_{10} = \Gamma_{10} + i\delta$, $d'_{20} = \Gamma_{20} + i(\Delta_1 + \Delta + \delta)$, $d_{21} = \Gamma_{21} + i\Delta'_1$, $d_{01} = \Gamma_{01} - i\delta$, $d'_{21} = \Gamma_{21} + i(\Delta_1 - \delta)$, and Γ_{ij} is the decay rate between energy levels $|i\rangle$ and $|j\rangle$. The real frequencies of the generated Stokes and anti-Stokes signals can be expressed as $\omega_S = \varpi_S + \delta$ and $\omega_{AS} = \varpi_{AS} - \delta$ respectively, where the introduced symbol θ can be viewed as the criterion for the linewidths of the generated signal.

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The boson-creation (-annihilation) operator satisfies the Heisenberg operator equation of motion in the dipole approximation:

$$d\hat{a}/dz = [\hat{a}, \hat{H}]/i\hbar = \kappa \hat{b}^+, \qquad (4)$$

$$d\hat{b}^+/dz = [\hat{b}^+, \hat{H}]/i\hbar = \kappa \hat{a}.$$
(5)

After some algebra, we get the photon numbers of the Stokes and anti-Stokes field at the output site of the medium [15,19]:

$$\begin{aligned} \langle \hat{a}_{\text{out}}^{+} \hat{a}_{\text{out}} \rangle &= \frac{1}{2} \left[\cos \left(2L \sqrt{AB} \sin \frac{\varphi_{1} + \varphi_{2}}{2} \right) \right. \\ &+ \cosh \left(2L \sqrt{AB} \cos \frac{\varphi_{1} + \varphi_{2}}{2} \right) \right] \frac{A}{B}, \quad (6) \end{aligned}$$

$$\langle \hat{b}_{\text{out}}^{+} \hat{b}_{\text{out}} \rangle = \frac{1}{2} \left[\cos \left(2L\sqrt{AB} \sin \frac{\varphi_{1} + \varphi_{2}}{2} \right) + \cosh \left(2L\sqrt{AB} \cos \frac{\varphi_{1} + \varphi_{2}}{2} \right) \right] \frac{B}{A}, \quad (7)$$

where *L* is the medium length, $\rho_{21(S)}^{(3)} = Ae^{i\varphi_1}$, $\rho_{20(AS)}^{(3)} = Be^{i\varphi_2}$, and *A* (*B*) and φ_1 (φ_2) are the modulus and phase angles of $\rho_{21(S)}^{(3)}$ ($\rho_{20(AS)}^{(3)}$), respectively.

When three beams E_1 , E'_1 , and E''_1 (from the same laser) are turned on [see Fig. 1(b)], a coherent FWM signal $(\mathbf{k}_F = \mathbf{k}_1 + \mathbf{k}''_1 - \mathbf{k}'_1)$ is produced. If we inject this FWM signal into the Stokes channel of the SP FWM [14], we obtain the PA FWM. Therefore, the gain of the Stokes channel is given by

$$g = \frac{1}{2} \left[\cos \left(2L\sqrt{AB} \sin \frac{\varphi_1 + \varphi_2}{2} \right) + \cosh \left(2L\sqrt{AB} \cos \frac{\varphi_1 + \varphi_2}{2} \right) \right].$$
(8)

B. Dressed PA FWM

Taking into account the dressing effects of E_2 and E_3 , Eqs. (2) and (3) can be rewritten as [16]

$$\rho_{21(S)}^{(3)} = -iG_{\rm AS}^* G_1^2 / (d_{21D} d_{01} d_{21D}'), \tag{9}$$

$$\rho_{20(\mathrm{AS})}^{(3)} = -iG_S^* G_1^2 / (d_{20D} d_{10} d'_{20D}), \qquad (10)$$

where $d_{21D} = \Gamma_{21} + i(\Delta_1 + \Delta) + |G_2|^2 / [\Gamma_{31} + i(\Delta_1 + \Delta - \Delta_2) + |G_1|^2 / \Gamma_{11}], \quad d_{20D} = \Gamma_{20} + i\Delta_1 + |G_2|^2 / [\Gamma_{30} + i(\Delta_1 - \Delta_2) + |G_1|^2 / \Gamma_{00}], \quad d'_{21D} = \Gamma_{21} + i(\Delta_1 - \delta) + |G_3|^2 / (\Gamma_{41} + i\Delta_3), \quad d'_{20D} = \Gamma_{20} + i(\Delta_1 + \Delta + \delta) + |G_3|^2 / (\Gamma_{40} + i\Delta_3).$

In addition, the polarization of the dressing field (E_2 or E_3) can be controlled by a quarter-wave plate (QWP) [see Fig. 1(b)]. We assume the *P*-polarization direction (along an optic axis of the crystal) to be the quantization axis, so the component perpendicular to it (*S* polarization) is decomposed into balanced left- and right-circularly-polarized parts, while the component parallel to it (*P* polarization) remains linearly polarized. So, the dressing terms in Eqs. (9) and (10) are replaced by $C_{g2,lin}^2(\cos^4\theta + \sin^4\theta)|G_2|^2$ and $C_{g2,cir}^2(2\cos^2\theta\sin^2\theta)|G_2|^2$, respectively. Here, $C_{g,lin}$ and $C_{g,cir}$ are Clebsch-Gordan (CG) coefficients for linear and circular polarization, respectively [20]. θ is the rotated angle between the QWP's axis and *P*-polarization direction. Because of the relationship

 $\kappa \propto \chi_i^{(3)} \propto \rho^{(3)}$, the output signals of this PA FWM process can be manipulated by the dressing fields (E_2 or E_3), e.g., the power, frequency detuning, and polarization.

C. Intensity noise correlation and intensity-difference squeezing

The output number of photons is given by $\langle \hat{a}_{out}^{+} \hat{a}_{out} \rangle$, which is proportional to the intensity since $I \propto \langle \hat{a}_{out}^{+} \hat{a}_{out} \rangle$. The intensity fluctuation is $\delta \hat{I}(t) = \hat{I}(t) - \langle \hat{I}(t) \rangle$. Therefore, the correlation between the intensity fluctuations of the output Stokes and anti-Stokes PA FWMs fields [19,21] can be obtained

$$G_{S,\mathrm{AS}}^{(2)}(\tau) = \frac{\langle [\delta \hat{I}_{S}(t_{S})] [\delta \hat{I}_{\mathrm{AS}}(t_{\mathrm{AS}})] \rangle}{\sqrt{\langle [\delta \hat{I}_{S}(t_{S})]^{2} \rangle \langle [\delta \hat{I}_{\mathrm{AS}}(t_{\mathrm{AS}})]^{2} \rangle}} = \frac{|\Psi_{S,\mathrm{AS}}|^{2}}{\sqrt{|C_{S}|^{2}|C_{\mathrm{AS}}|^{2}}},$$
(11)

where $\tau = \tau_{AS} - \tau_s$, $\tau_j = t_j - r_j/c$, r_j is the optical path from the output surface of the crystal to the *j*th detector (j = 1, 2), t_j is the trigger time, $\langle [\delta \hat{I}_S(t_S)] [\delta \hat{I}_{AS}(t_{AS})] \rangle$ is the cross-correlation function between the intensity fluctuations of E_{AS} and $E_S, C_S = \sqrt{R_s} \int d\omega_S \sinh^2(\kappa L)$, $C_{AS} = \sqrt{R_{AS}} \int d\omega_A \sinh^2(\kappa L)$, V_Q is the quantization volume, and $R_{S,AS} = V_Q^{1/3} E_{S,AS}^2 / (2\pi\nu_{S,AS})$ are self-correlation functions of E_S and E_{AS} , respectively, where $\Psi_{S,AS}(\tau) = i\pi E_1^2 E_S E_{AS} \omega_1 \int e^{-i\delta \tau} \chi^{(3)}(\delta) d\delta$.

Considering the Boltzmann distribution with finite temperature, the two-photon envelope function can be obtained by performing a Fourier transform on the thirdorder nonlinear susceptibility, $\Psi_{s-as}(\tau) = i\pi E_1^2 E_S E_{AS} \omega_1$ $\Gamma_{21} - \Gamma_{01}$][$e^{-\Gamma_{-}\tau} - e^{-i\Delta_{1}\tau}e^{-\Gamma_{+}\tau}$] [22]. In addition, taking into account the interaction between the sample and coupling fields, the broadened linewidth of the measured SP FWM signal is $\Gamma_{\pm} = \Gamma_{pop} - \Gamma(\pm \delta) + \Gamma_{ion-spin} +$ $\Gamma_{\text{ion-ion}} + \Gamma_{\text{phonon}}$, where $\Gamma_{\text{pop}} = (2\pi T_1)^{-1}$ depends on the location of the energy level in phase space, with T_1 describing the population decay time, and the term $\Gamma(\pm\delta)$ represents the location of the energy level, which can be dressed by the coupling field. The last three terms $(\Gamma_{\text{ion-spin}} + \Gamma_{\text{ion-ion}} + \Gamma_{\text{phonon}})$ are components of $(2\pi T_2^*)^{-1}$ (the reversible transverse relaxation time T_2^*). $\Gamma_{\text{ion-spin}}$ is related to the ion-spin coupling effect of the individual ion. $\Gamma_{\text{ion-ion}}$ is determined by the interaction among the rareearth ions and can be controlled by the power of the external field and impurity concentration. Γ_{phonon} is related to the sample temperature. To quantify $\Gamma_{\text{ion-ion}}$, P(t) is introduced $P(t)_a = \exp[-c_H \sum_{n=6,8,10,12,13,14} (A_{nH}/R_H^n)]$ and $P(t)_b = \exp[-c_D \sum_{n=5,6,7} (A_{nD}/R_D^n)]$, where A_{nH}/R_D^n A_{nD} is the van der Waals attractive force coefficient, R_H^n/R_D^n is the distance of the nucleus, c_H and c_D represent the population densities at the triplet energy level ${}^{3}H_{4}$ and singlet energy level ${}^{1}D_{2}$, respectively, and can be controlled by the pump power. $\sum (A_{nH}/R_{H}^{n})$ and $\sum (A_{nD}/R_{D}^{n})$ represent the induced dipole-dipole interaction of states *H*-*H* and *D*-*D*, respectively.

The degree of two-mode intensity-difference squeezing is given by [19,23,24]

$$sq = \log_{10} \frac{\langle \delta^2(\hat{I}_S - \hat{I}_{AS}) \rangle}{\langle \delta^2(\hat{I}_S + \hat{I}_{AS}) \rangle} \approx \log_{10} \frac{\langle \delta^2(\hat{N}_S - \hat{N}_{AS}) \rangle}{\langle \delta^2(\hat{N}_S + \hat{N}_{AS}) \rangle}$$
$$= -\log_{10}(2g - 1), \tag{12}$$

where $\langle \delta^2(\hat{N}_S - \hat{N}_{AS}) \rangle$ is the mean square deviation of the intensity difference, and $\langle \delta^2(\hat{N}_S + \hat{N}_{AS}) \rangle$ is the mean square deviation of the intensity sum of the coherent laser beams.

D. Multiorder fluorescence

We adopt the perturbation theory to investigate the multiorder-fluorescence (MFL) signal [25,26]. When E_1 and E_2 are open, the MFL signal is generated in the Λ -type-level system of Pr^{3+} : Y₂SiO₅. Taking into account the dressing effects of E_1 and E_2 and the perturbation chains $\rho_{00}^{(0)\omega_1} \rightarrow \rho_{20}^{(1)-\omega_1}\rho_{22}^{(2)-\omega_2}\rho_{32}^{(3)\omega_2} \rightarrow \rho_{22}^{(4)}$, the intensity of MFL signal can be described by the diagonal density matrix element $\rho_{22}^{(4)}$, which is given by [14]

$$\rho_{\rm MFL}^{(4)} = \rho_{22}^{(4)} = |G_2|^2 |G_1|^2 / [d_{20D} \Gamma_{00} d_{32} \times (\Gamma_{22} + |G_2|^2 / d_{32} + |G_1|^2 / d_{20})], \quad (13)$$

where $d_{32} = \Gamma_{32} + i\Delta_2$.

III. RESULTS AND DISCUSSION

A. System preparation

The sample (a 3-mm Pr^{3+} : Y₂SiO₅ crystal) is held at 77 K in a cryostat (CFM-102). Three transform-limited tunable dye lasers (narrow scan with a 0.004-cm⁻¹ linewidth) pumped by an injection-locked single-mode Nd: YAG laser (Continuum Powerlite DLS 9010, 10-Hz repetition rate, 5-ns pulse width) are used to generate the pumping fields E_1, E'_1 , $E_1''(\omega_1, \Delta_1), E_2(\omega_2, \Delta_2), \text{ and } E_3(\omega_3, \Delta_3).$ The diameter of all beams is 0.8 mm. The polarizations of the laser beams are controlled by inserting wave plates into the corresponding beam paths. In such multilevel atomlike system, one can obtain the PA FWM with an injecting coherent FWM signal $(\mathbf{k}_F = \mathbf{k}_1 + \mathbf{k}_1'' - \mathbf{k}_1')$. Note that the generated signals $(\mathbf{E}_S, \mathbf{k}_S)$ $E_{\rm AS}$) are quantum correlated [27,28]. Figure 1(b) shows the experimental arrangement taking into account the above phase-matching condition. The generated signals (E_S, E_{AS}) are associated with MFL signals and detected by photomultiplier tubes. Such PA FWM process can be doubly dressed by applying dressing fields E_1 and E_2 (or E_3) or triply dressed by applying all three dressing fields E_1 , E_2 , and E_3 simultaneously.

B. Two-mode experimental results

Nonlinear processes can occur easily in the paraxial direction of the incident laser beam. In the current experiment, the PA FWM process occurs, which is well interpreted by a self-diffraction-type FWM process in which a strong pumping field E_1 is mixed with two weak fields E_s and E_{AS} as shown in Fig. 1(a) (middle panel). The parameter space to be searched for in our investigation of the dressed PA FWM together with the MFL is large, with the frequency detuning Δ_1 of pumping field E_1 and the powers and the polarization states of both dressing fields E_2 and E_3 as externally controlled variables. In addition, we compare the dressing effects of two structures in Fig. 1(a), i.e., E_2 dressing in a Λ -type three-level subsystem of an individual Pr^{3+} ion and E_3 dressing in a V-type three-level subsystem of a hetero-nuclear-like molecule.

Since the generated E_s and E_{AS} are twin beams and have similar properties, we choose only E_s and its MFL to show the properties under various dressing conditions. First of all, we analyze the accompanied MFL spectra [see Fig. 2(a)] under various dressing conditions in the Λ -type subsystem. The typical linewidths of MFL signals are about 30 GHz. On the one hand, they are broadened by phonons (Γ_{phonon}) from the lattice heat vibration and the power ($\Gamma_{ion-ion}$) of the pumping field. On the other hand, they are balanced by the dressing effect [$\Gamma(\pm \delta)$] [29]. At a relatively low power of $P_1 = 1$ mW [Fig. 2(a1)], the MFL has a Lorentzian line shape with a small Autler-Townes (AT) splitting [14], which is induced by setting $P_2 = 3$ mW. One way to explain these observed effects is by using the dressed-stated picture.



FIG. 2. Measurements of the PA FWM (E_s) and MFL excitation spectra associated with their lifetimes under specified experimental parameters. (a)–(d) Dressed spectra and lifetimes. (a) The MFL spectra, (b) the PA FWM spectra E_s , (c) temporal MFL, and (d) E_s intensity. The parameters inside the parentheses in (b1), (b2), and (b4) are E_1 power, E_2 power, and E_2 polarization by QWP, where the linear and circular polarizations are denoted as $\theta = 0^\circ$ and $\theta = 45^\circ$ of the QWP, respectively. In (b3), the parameters are E_1 power, E_2 power, and E_3 power. $G_1 = 25$ GHz at 3 mW.

The power of E_2 splits the energy level $|2\rangle$ into $|G_{2\pm}\rangle$. From the Hamiltonian equation $H|G_{2\pm}\rangle = \lambda_{\pm}|G_{2\pm}\rangle$, we obtain $\lambda_{\pm} = [\Delta_2 \pm (\Delta_2^2 + 4|G_2|^2)^{1/2}]/2.$ Therefore, the splitting distance between $|G_{2\pm}\rangle$ is $2\sqrt{\Delta_2^2 + 4|G_2|^2}$, as shown in Fig. 2(a1). Next, by increasing $P_1 = 3$ mW [Fig. 2(a2)], the MFL is suppressed by the double-dressing effect of E_1 and E_2 which appears as a suppression dip [see Eq. (13)]. Here, the baseline comes from another fluorescence process excited by E_2 . Physically, this phenomenon can be attributed to the nest-type dressing term d_{20} in Eq. (13) [14,20]. The suppressing ability of E_1 increases as the detuning Δ_1 gets closer to resonance. However, this situation changes at the resonant region of $\Delta_1 = \Delta_2 = 0$, in which a peak of E_S due to the high power of E_1 overlaps with the dip. Third, when E_2 and E_3 are both turned on simultaneously, the triple-dressing effect must be considered. As demonstrated in Fig. 2(a3), the MFL is suppressed completely. If the beam E_2 is set to be circularly polarized [Fig. 2(a4)] while all other parameters remain the same as those in Fig. $2(a^2)$, one can easily see that the dressing effect in such case is stronger than that in the linear case in Fig. 2(a2). Since the CG coefficients may be different for different transitions between Zeeman sublevels, the Rabi frequency can vary with polarization even if the frequency and power of the laser field remain unchanged. For example, the CG coefficients, $C_{g,cir}$ (circular polarization) and $C_{a,\text{lin}}$ (linear polarization) are $\sqrt{4/35}$ and $\sqrt{1/35}$, respectively with M = 1/2. So, the dressing terms in Eq. (13) are replaced by $C_{g2,\text{lin}}^2(\cos^4\theta + \sin^4\theta)|G_2|^2$ and $C_{q2,cir}^2(2\cos^2\theta\sin^2\theta)|G_2|^2$, respectively. Thus, the ratio between dressing term of the circular and linear case is expressed as $C_{g2,cir}^2/C_{g2,lin}^2 = 4$, with $\theta = 45^\circ$ and M = +1/2, which indicates that the dressing effects in the circularly polarized subsystems are far greater than those in the linearly polarized subsystems.

In addition, one can find that the dressed state, one of the most important consequences of the dressing effect of beam E_2 , makes the intensity curves in the time domain with $\Delta_1 = \Delta_2 = 0$ show double peaks of the AT splitting configuration. There exist two peaks, which correspond to the locations of the zero delay time and a longer delay time [30], as displayed in Figs. 2(c2)-2(c4). The obvious delay of the right peak in Fig. 2(c1) is caused by the residual particles in $|G_{2+}\rangle$ transferring to $|G_{2-}\rangle$ through phonon-assisted nonradiative transition, which is mainly determined by acoustic phonons at low temperature. As the power of either E_1 or E_2 increases, such space (time delay) between two peaks [Fig. 2(c)] gets larger, which can be attributed to the energy-level splitting by the dressing effect [corresponding to the AT splitting in the spectrum in Fig. 2(a)]. The curves in Figs. 2(d) and 2(d) are the dressed PA FWM spectra together with their lifetimes corresponding to each fluorescence case [30]. Based on the analysis of the above florescence signals, one can easily determine the physical mechanism behind each output E_S as shown in Figs. 2(b) and 2(d). In other words, the dressing effect makes the intensity of the PA FWM decrease and the lifetime longer, whereas the dressing effect of the circularly polarized field is stronger than that for the linear case [20]. However, since the PA FWM signal is insensitive to the dressing field, there are no AT splittings in both the spectrum and time domain, as shown in Figs. 2(b) and 2(d), respectively.

Now, we focus on the intensity noise correlation and intensity-difference squeezing between the output beams E_S and E_{AS} of the dressed PA FWM process as shown in Fig. 3. Figure 3(a) shows the noise correlations under various control conditions. First, the correlation levels at the resonance and off-resonance positions are differentthe correlation is reduced at the suppression dip position [shown in Fig. 2(a), satisfying suppression condition $\Delta_1 - \Delta_2 = 0$; Fig. 2(a1), $\Delta_1 = 0$], while it is enlarged at the enhanced-peak position [shown in Fig. 2(a), satisfying the enhancement condition $\Delta_1 + \lambda_{\pm} = 0$; Fig. 2(a2), $\Delta_1 = 200$ GHz]. To investigate in detail the role of the dressed states on the correlation level, we plot a frequency dependence of the maximum correlation value on the discrete frequency detuning Δ_1 presented as square points in Fig. 3(b1). The two-mode correlation $G_{S,AS}^{(2)}(\tau)$ [Eq. (11)] and squeezing (sq) [Eq. (12)] are determined by the nonlinear gains in Eq. (8), which can be modified by the dressing effect in Eqs. (9), (10), and (13) [31]. The curve includes three regions: the resonance, near resonance, and far off resonance, respectively. At the far off resonance, the nesting double-dressing configuration $[d_{21D}]$ and d_{20D} in Eqs. (9) and (10)] reduces to zero, and the nonlinear gain [Eq. (8)] gets the maximum value. At last, the maximum correlation is obtained. As Δ_1 is close to being near resonance, the correlation value becomes smaller and smaller due to the nonlinear gain (q) decrease, and the correlation reaches its minimum value at $\Delta_1 = 100$ GHz. Similarly, the correlation value is minimized at $\Delta_1 =$ -100 GHz [the square points in Fig. 3(b1)]. However, in the region $|\Delta_1| \leq 100$ GHz, the dressing effect due to E_2 cannot be neglected. Therefore, at resonance, the nesting double-dressing configuration $(d_{20} \text{ and } d_{21})$ makes the correlation much smaller but not to its minimum value due to the action of dressing field E_2 , as shown in the square points in Fig. 3(b1). In addition, the modulated correlation time has the opposite behavior depicted with circular points in Fig. 3(b1). The single-dressing effect can result in the increased lifetime of the PA FWM and the decreased intensity of the PA FWM process [29]. The lifetime of the PA FWM process is inversely proportional to the decay rate of the PA FWM process, where the dressing results between the lifetime of the PA FWM process and the correlation time of $G_{S,AS}^{(2)}(\tau)$ are coincident with each other because the lifetime of the PA FWM process [Fig. 2(d)] is modulated in the same way as shown in the circular curve in Fig. 3(b1). As we discuss above, the correlation time and



FIG. 3. Measured intensity noise correlation and squeezing. (a),(c) Measured intensity noise correlation and intensity-difference squeezing between output beams E_s and E_{AS} , where the PA FWM process is dressed by E_2 . All experimental conditions are identical except Δ_1 [(a1), $\Delta_1 = 0$] and [(a2), $\Delta_1 = 200$ GHz], polarization state of the dressing field E_2 (a1) $\theta_2 = 0^\circ$ and (a3) $\theta_2 = 45^\circ$, and E_2 power (a1) $P_2 = 5$ mW, and (a4) $P_2 = 1$ mW, respectively. (b) Frequency detuning, power and polarization dependences of the maximum correlation value $G^{(2)}(0)$ (squares), and correlation time $\Delta \tau$ (circles). (d) Dependences of the squeezing value at the analysis frequency 1.5 MHz (squares) and decay rate (circles) of the output beam E_s , respectively, corresponding to the cases in (b). Note that the squares denote the case dressed by E_3 . (e),(f) Measured intensity noise correlation and intensity-difference squeezing between output beams E_s and E_{AS} at (1) $\Delta_1 = 200$ GHz, (2) 60 GHz, and (3) 0, which are dressed by E_2 and E_3 simultaneously. (4) Frequency dependence of the maximum correlation and squeezing degree on the frequency detuning Δ_1 .

decay rate are still valid, as shown by the circular points in Figs. 3(b2), 3(b3), and 3(d2), and 3(d3), and the degree of correlation [square points in Fig. 3(b)] is inversely proportional to the correlation time [circular points in Fig. 3(b)]. Now, we use the Cauchy-Schwarz inequality $G_{S,AS}^{(2)}(\tau_1) \leq 1$ to check our experimental result [Fig. 3(a2)]. The measured correlation at off resonance is about 1.5, which clearly violates of the Cauchy-Schwarz inequality, proving that there is a nonclassical correlation between E_S and E_{AS} .

Next, we focus on the power and polarization dependences of the intensity noise correlation on E_2 . Figures 3(a1) and 3(a4) show the correlation curves at high power $(P_2 = 5 \text{ mW})$ and low power $(P_2 = 1 \text{ mW})$, respectively, when $\Delta_1 = 0$ and $\theta_2 = 0^{\circ}$ (linear polarization). As the power of the dressing field increases, the correlation increases at first due to the dominant gain by the terms d_{20} and d_{21} , and then it becomes worse due to the dressing effect from the dressed term in Eq. (9), as shown by the square points in Fig. 3(b2). Figures 3(a1) and 3(a3) show the correlation curves at linear polarization ($\theta_2 = 0^\circ$) and circular polarization ($\theta_2 = 45^\circ$), respectively, when $\Delta_1 = 0$ and $P_2 = 5$ mW. As site I of the Pr³⁺ ion is much more sensitive to the circular polarization, one finds a similar behavior [see the square points in Fig. 3(b3)]. The competition between the linear component $C_{g2,\text{lin}}^2(\cos^4\theta + \sin^4\theta)|G_2|^2$ and circular component $C_{q2,cir}^2(2\cos^2\theta\sin^2\theta)|G_2|^2$ can well interpret such phenomena. Considering the relationship $\kappa \propto \chi_i^{(3)} \propto \rho^{(3)}$, the nonlinear gain can be modified by the polarizations of the dressing fields (E_2 or E_3). Specifically, the intensity ($|\rho^{(3)}|^2$) of the PA FWM is suppressed when the polarization of the dressing field changes from linear to circular due to the stronger dressing effect in the circular case. Therefore, $|\Psi_{s-as}|^2$ in Eq. (11) becomes smaller, and this leads to a lower correlation degree than that for the linearly polarized case [Figs. 3(a1) and 3(a3)]. Similarly, according to Eq. (12), the degree of squeezing decreases when the dressing field is circularly polarized compared with the linear case [Figs. 3(b1) and 3(b3)].

Figure 3(c) shows the intensity-difference squeezing (lowest curve in each panel) in contrast to the total noise (highest curve in each panel) or the shot-noise level [middle curve in Fig. 3(c2)]. Specifically, the highest curve in each panel is the total noise of the two output beams. The shotnoise level (SNL) [dashed curves in Figs. 3(c) and 3(f)] for the PA FWM process is defined as the intensity-difference noise on a pair of equal power beams produced from a coherent laser by a beam splitter with equal power as the sum of E_S and E_{AS} [23]. As shown in Fig. 3(c2), the intensity-difference squeezing measured here is -4.5 dB, which is lower than the SNL. One finds that the doubledressing results of squeezing [Eq. (12)] have the same behavior as the correlation [Eq. (11)], which are determined by the dressed nonlinear gain in Eq. (8), as shown by the square points in each panel in Fig. 3(d). Therefore, the degree of intensity-difference squeezing of the output beams E_S and E_{AS} depends crucially on the correlation functions [27,28].

When the dressing fields E_2 and E_3 are turned on simultaneously, a triple-dressed PA FWM process can be obtained [32]. Different from the case of the double-dressed PA FWM, the dressed results in Eq. (12) can be switched at $\Delta_1 = 0$. For example, the correlation measured here is



FIG. 4. (a) Intensity noise correlation curves between E_s and E_{AS} versus delayed time τ with changing power of E_2 , with (a1) 6 mW, (a2) 8 mW, and (a3) 12 mW, respectively. (b1) $P_2 = 6$ mW and $\omega = 1.5$ MHz. The lower curve and upper curve are the noise level of intensity-difference squeezing and intensity-sum squeezing versus analysis frequency Ω , respectively. (b2) $P_2 = 8$ mW. The intensity-sum squeezing and intensity-difference squeezing have the same noise level and are indistinguishable. (b3) $P_2 = 12$ mW and $\omega = 1.5$ MHz. The lower curve and upper curve are the noise level of the intensity-sum squeezing and intensity-sum squeezing and intensity-difference squeezing and intensity-difference squeezing and intensity-sum squeezing and intensity-difference squeezing and intensity-sum squeezing and intensity-difference squeezing.

about 1.4 [Fig. 3(e1)], which is reduced in comparison with that in Fig. 3(a1). However, there is also a nonclassical correlation between E_s and E_{AS} , since the Cauchy-Schwarz inequality is violated clearly. On the other hand, due to the different polarization responses of site I and site II, the frequency dependence of the maximum correlation value on Δ_1 presents an inverted Lorentzian line shape [see Fig. 3(e4)], while the double-dressed case is a normal Lorentzian line shape with a central peak [see Fig. 3(b1)]. Similar behaviors can be found for the intensity-difference squeezing [Eq. (13)] as shown in Fig. 3(f4) (triple dressed) and Fig. 3(d1) (double dressed). Thus, the intensitydifference squeezing [Figs. 3(d) and 3(f4)] is proportional to the corresponding noise correlation [Figs. 3(b) and 3(e4)] of the PA FWM process.

In addition, we not only verify that the intensity-difference squeezing and intensity noise correlation can be easily manipulated by several parameters in Fig. 3, but we also show that the correlation and squeezing can be controlled by the relative nonlinear phase shift caused by the dressing beam. As shown in Fig. 4(a1), with $P_2 = 6$ mW, the amplitude of the correlation peak at delay time $\tau = 0$ is 1.3. The Cauchy-Schwarz inequality is violated in Fig. 4(a1)and nonclassical correlation between E_S and E_{AS} is demonstrated. As $P_2 = 8$ mW, the amplitude is about 0, as shown in Fig. $4(a^2)$, and there do not exist correlation and squeezing. In particular, the intensity fluctuation is switched from correlated to anticorrelated if $P_2 = 12$ mW, as shown in Fig. 4(a3). These results can be explained by the nonlinear refractive index of the Kerr medium. Since the dressing state created by E_2 can modulate the nonlinear refractive index of

the Kerr medium that results from the cross-phase modulation (XPM), the relative nonlinear phase $\Delta \varphi = \varphi_S - \varphi_{AS} =$ $2(k_S n_2^S - k_{AS} n_2^{AS})|E_2|^2 e^{-r^2} z/n_1$ between the Stokes and anti-Stokes signals is significantly modulated. Here, φ_S (φ_{AS}) is the nonlinear phase induced on the Stokes (anti-Stokes) signal. The Kerr effect is associated with nonlinear refractive index n_2 (corresponding to the third-order nonlinear response) and intensity of light I (n_2I , $n_2 =$ $\operatorname{Re}\chi^{(3)}/\varepsilon_0 cn_1$). To be specific, by setting $P_2 = 6$, 8, and 12 mW, the relative nonlinear phase $\Delta \varphi$ changes to $\Delta \varphi = 0$, $\pi/2$, and π , respectively. Correspondingly, the correlation [Eq. (12)] switches from positive to zero and then to negative. Moreover, by changing $\Delta \varphi$, Figs. 4(b1)–4(b3) show that the intensity-difference signal [Eq. (13)] can be switched to either higher or lower than the total noise signal, which corresponds to squeezing or antisqueezing, respectively. Therefore, the intensity fluctuation correlation and the intensity-difference squeezing of the output beams E_S and $E_{\rm AS}$ depend crucially on the relative nonlinear phase induced by XPM.

C. Triplet beams by the PA SWM process

Furthermore, we investigate the three-mode correlation and squeezing of the PA SWM with an injecting coherent FWM. Different from the generated twin beams by the SP FWM process, laser fields E_2 and E_3 both at large detunings are set to be certain angles with E_1 satisfying the phase-matching condition. Thus, mutually correlated triplet beams can be produced by a SP SWM process with the phase-matching condition $\mathbf{k}_{S1} + \mathbf{k}_{S2} + \mathbf{k}_{S3} = \mathbf{k}_1 + \mathbf{k}_{S3}$ $\mathbf{k}_2 + \mathbf{k}_3$. Since such SP SWM process [14] can be mimicked by cascading two involved closed-loop SP FWM processes $(\mathbf{k}_{S1} + \mathbf{k}_{S2} = \mathbf{k}_1 + \mathbf{k}_2$ and $\mathbf{k}_{S1} + \mathbf{k}_{S3} =$ $\mathbf{k}_1 + \mathbf{k}_3$) [Fig. 5(a)], one can write the Hamiltonian as $H_I = i\hbar\kappa_1 \hat{a}_{S1}^{\dagger} \hat{a}_{S2}^{\dagger} + i\hbar\kappa_2 \hat{a}_{S1}^{\dagger} \hat{a}_{S3}^{\dagger} + \text{H.c., where } \hat{a}_{S1}^{+}, \hat{a}_{S2}^{+}, \hat{a}_{S3}^{+}$ are the boson creation operators of the three generated fields, and $\kappa_1 = -i \varpi_{S1} \chi_1^{(3)} E_1 E_2 / 2$ and $\kappa_2 = -i \varpi_{S1} \chi_2^{(3)}$ $E_1E_3/2$ are the third-order nonlinear susceptibility of



FIG. 5. (a) *N*-type four-level atomlike system in Pr^{3+} : Y_2SiO_5 for triple-photon generation by a SP SWM process composed of Λ -type and *V*-type three-level subsystems. (b) New experimental scheme for the SP SWM process with the phase-matching condition $\mathbf{k}_{S1} + \mathbf{k}_{S2} + \mathbf{k}_{S3} = \mathbf{k}_1 + \mathbf{k}_2 + \mathbf{k}_3$.

cascading two $(\chi_1^{(3)} \text{ and } \chi_2^{(3)})$ involved SP FWM processes. Therefore, one can easily get the dynamic equations as

$$d\hat{a}_{S2}/dt = \kappa_1 \hat{a}_{S1}^{\dagger}, d\hat{a}_{S1}/dt = \kappa_1 \hat{a}_{S2}^{\dagger} + \kappa_2 \hat{a}_{S3}^{\dagger}, d\hat{a}_{S3}/dt = \kappa_2 \hat{a}_{S1}^{\dagger}.$$
(14)

$$G^{(3)} = \frac{\langle [\delta \hat{I}_{S1}(t_{S1})] [\delta \hat{I}_{S2}(t_{S2})] [\delta \hat{I}_{S3}(t_{S3})] \rangle}{\sqrt{\langle [\delta \hat{I}_{S1}(t_{S1})]^2 \rangle \langle [\delta \hat{I}_{S2}(t_{S2})]^2 \rangle \langle [\delta \hat{I}_{S3}(t_{S3})]^2 \rangle}} = \frac{(H_{S1S2S3})}{\langle I_{S1}(t_{S1}) I_{S1}(t$$

where H_{S1S2S3} is the cross-correlation function of intensity between E_{S1} , E_{S2} , and E_{S3} , and H_{Si} is the one-order correlation function of the intensity. C_{SiSi} is the crosscorrelation function between the intensity fluctuations of E_{Si} and E_{Si} $(i, j = 1, 2, 3, i \neq j)$. C_{Si} is the self-correlation function. The conditional intensity-difference squeezing for the three-mode case can be given by [24,31]

$$sq = \log_{10} \frac{\langle \delta^2(\hat{N}_{S1} - \hat{N}_{S2} - \hat{N}_{S3}) \rangle}{\langle \delta^2(\hat{N}_{S1} + \hat{N}_{S2} + \hat{N}_{S3}) \rangle} \approx 2\log_{10} \frac{g_1^2 - g_2^2 - g_3^2}{g_1^2 + g_2^2 + g_3^2},$$
(16)

where $g_1 = [\kappa_2^2 + \kappa_1^2 \cosh(\Omega L)]/(\kappa_2^2 + \kappa_1^2), g_2 = \kappa_1 \sinh(\Omega L)/(\kappa_2^2 + \kappa_1^2)$ $\sqrt{\kappa_2^2 + \kappa_1^2}$, and $g_3 = \kappa_1 \kappa_2 (\cosh(\Omega L) - 1) / \kappa_2^2 + \kappa$.

When beams E_1 , E_2 , and E_3 are turned on simultaneously, as shown in Fig. 5(a), a PA SWM process with the phase-matching condition $\mathbf{k}_{S1} + \mathbf{k}_{S2} + \mathbf{k}_{S3} = \mathbf{k}_1 + \mathbf{k}_{S3} = \mathbf{k}_1$ $\mathbf{k}_2 + \mathbf{k}_3$ can be obtained in the *N*-type four-level system. Figure 5(b) shows the experimental arrangement for meeting the PA SWM phase-matching condition. To satisfy the requirement for such PA SWM process, two PA FWM processes share the pumping beam E_1 and output beam E_{S1} in both the frequency domain and spatial domain by using a specially designed experimental configuration (fields E_2 and E_3 both counterpropagating with E_1 at a certain angle to meet the phase-matching condition). The major difference between the current PA SWM experimental scheme [Fig. 5(a)] and that in Fig. 1(a) is the frequency detuning set for E_1 , E_2 , and E_3 . In addition, due to the angle between \mathbf{k}_2 , \mathbf{k}_3 , and \mathbf{k}_1 , the generated SWM signal cannot be obtained in the same direction of the FWM when the detector is placed as shown in Fig. 1(a). Therefore, E_2 and E_3 are only dressing fields for the SP FWM in Fig. 1(a) while E_1 , E_2 , and E_3 are all generating fields for the SP SWM.

Figure 6 depicts the triple-beam correlation and intensity-difference squeezing results. Two sets of frequency

Similar to the PA FWM process, one can calculate the output results from these equations. Here, we are concerned about the properties of the output signals from this PA SWM process with an injecting coherent FWM $(\mathbf{k}_F = \mathbf{k}_1 + \mathbf{k}''_1 - \mathbf{k}'_1)$ [15], and then we extend the $G^{(2)}(\tau)$ function for the two-mode case to the three-mode correlation function $G^{(3)}(\tau)$ as

$$\frac{|\langle t_{S1} \rangle| |\delta I_{S2}(t_{S2})| |\delta I_{S3}(t_{S3})| \rangle}{\langle s_{S1} \rangle|^2 \rangle \langle [\delta \hat{I}_{S3}(t_{S3})]^2 \rangle} = \frac{\langle H_{S1S2S3} - H_{S3}C_{S1S2} - H_{S2}C_{S1S3} - H_{S1}C_{S3S2} + 2H_{S1}H_{S2}H_{S3})}{\sqrt{|C_{S1}|^2(|C_{S2}|^2 + |C'_{S2}|^2)|C_{S3}|^2}},$$
(15)

detunings of E_1 are set at off resonance [$\Delta_1 = 200$ GHz, Fig. 6(a)] and on resonance $[\Delta_1 = 0, \text{ Fig. 6(b)}]$, respectively. Three-mode correlation [Eq. (15)] and squeezing [Eq. (16)] are determined by the dressed nonlinear gains [31]. By comparing the results of triple-beam correlation and intensity-difference squeezing, one finds that the maximum correlation value at off resonance is bigger than the on-resonance case, which is similar to that shown for the twin beams. However, the correlation level is weaker than that for the case of triple-dressed twin beams since the correlation condition is more stringent as shown in Eq. (15). Similar behavior occurs with the intensitydifference squeezing. In contrast to the twin beams, the SNL for the PA SWM process becomes the intensity-sum noise on three coherent laser beams with equal power as the sum of E_{S1}, E_{S2} , and E_{S3} . In Eq. (16), $\langle \delta^2(\hat{N}_{S1} + \hat{N}_{S2} + \hat{N}_{S3}) \rangle$



FIG. 6. Three-mode noise correlation and intensity-difference squeezing of E_{S1} , E_{S2} , and E_{S3} . Experimental conditions are set as follows: (a),(b) E_1 , E_2 , and E_3 are linearly polarized, (c) E_1 is linearly polarized, while E_2 and E_3 are circularly polarized.

is the total noise of the three coherent laser beams. Based on the cascade processes [24], $\langle \delta^2(\hat{N}_{S1} - \hat{N}_{S2} - \hat{N}_{S3}) \rangle$ is the intensity noise difference of three output beams. Because of the more stringent condition of the threemode direct correlation, the squeezing value is smaller than in the dressed twin-beam case. We get a -3.5 dB squeezing in Fig. 6(a3), but the same role played by the dressed state is still true for the squeezing results; i.e., it reduces the squeezing.

Next, we focus on the case when both E_2 and E_3 are either linearly polarized [Fig. 6(b)] or circularly polarized [Fig. 6(c)] while E_1 remains linearly polarized. Apparently, the correlation and squeezing with linear polarization are better than the case with circular polarization, which is similar to the twin-beam case with single dressing field E_2 only (Fig. 3).

IV. CONLUSIONS

We investigate the generated twin beams by the PA FWM process and triplet beams by the PA SWM process associated with the MFL signals in a PR^{3+} : Y₂SiO₅ crystal. First, the degrees of intensity noise correlation and intensity-difference squeezing between the output beams E_S and E_{AS} of the PA FWM process are determined by the nonlinear gain, which can be controlled by the dressing variables. The correlation at the resonant position can attain a higher value due to the doubledressing effect; however, such correlation is reduced in the case of the triple-dressing effect. Second, the correlation of the PA FWM can change to anticorrelation by the nonlinear phase shift, which is induced by the external dressing beam, and the noise level of the intensity-difference squeezing is switched synchronously. Finally, we investigate the intensity noise correlation and intensity-difference squeezing of the triplet beams generated by the PA SWM process, which is well interpreted by two cascaded nonlinear processes. The correlation level is weaker than the case of twin beams since the three-mode correlation condition is more stringent. Meanwhile, the squeezing value is also smaller than the twin-beam case. Similarly, the polarized dark state still plays the same role in the results. Such results can find potential applications in engineering three-channel entangled imaging on chip.

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